

< C band internally matched power GaAs FET >

MGFC42V6472

6.4 – 7.2 GHz BAND / 16W

DESCRIPTION

The MGFC42V6472 is an internally impedance-matched GaAs power FET especially designed for use in 6.4 – 7.2 GHz band amplifiers. The hermetically sealed metal-ceramic package guarantees high reliability.

FEATURES

Class A operation

Internally matched to 50(ohm) system

- High output power
P1dB=18W (TYP.) @f=6.4 – 7.2GHz
- High power gain
GLP=8dB (TYP.) @f=6.4 – 7.2GHz
- High power added efficiency
P.A.E.=30% (TYP.) @f=6.4 – 7.2GHz
- Low distortion [item -51]
IM3=-45dBc (TYP.) @Po=31dBm S.C.L

APPLICATION

- item 01 : 6.4 – 7.2 GHz band power amplifier
- item 51 : 6.4 – 7.2 GHz band digital radio communication

QUALITY

- IG

RECOMMENDED BIAS CONDITIONS

- VDS=10V • ID=4.5A • RG=25ohm Refer to Bias Procedure

Absolute maximum ratings (Ta=25°C)

Symbol	Parameter	Ratings	Unit
VGDO	Gate to drain breakdown voltage	-15	V
VGSO	Gate to source breakdown voltage	-15	V
ID	Drain current	12	A
IGR	Reverse gate current	-40	mA
IGF	Forward gate current	84	mA
PT *1	Total power dissipation	78.9	W
Tch	Channel temperature	175	°C
Tstg	Storage temperature	-65 to +175	°C

*1 : Tc=25°C

Electrical characteristics (Ta=25°C)

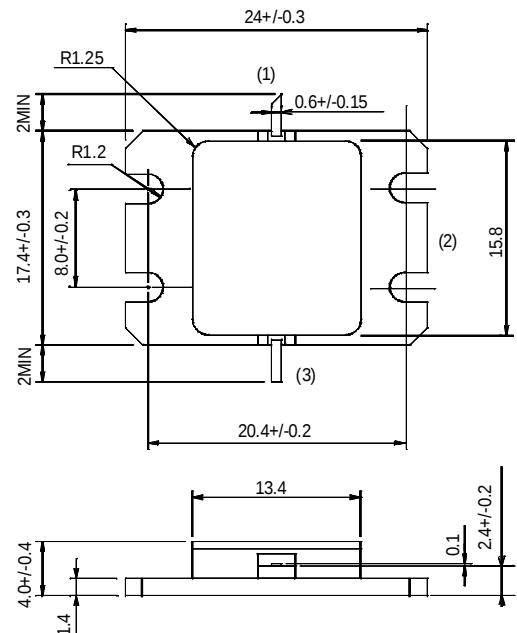
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
IDSS	Saturated drain current	VDS=3V, VGS=0V	-	9	12	A
gm	Transconductance	VDS=3V, ID=4.4A	-	4	-	S
VGS(off)	Gate to source cut-off voltage	VDS=3V, ID=80mA	-2	-3	-4	V
P1dB	Output power at 1dB gain compression	VDS=10V, ID(RF off)=4.5A	41.5	42.5	-	dBm
GLP	Linear Power Gain	f=6.4 – 7.2GHz	7	8	-	dB
ID	Drain current		-	4.5	-	A
P.A.E.	Power added efficiency		-	30	-	%
IM3 *2	3rd order IM distortion		-42	-45	-	dBc
Rth(ch-c) *3	Thermal resistance	delta Vf method	-	-	1.9	°C/W

*2 : item -51 , 2 tone test, Po=31dBm Single Carrier Level , f=7.2GHz, delta f=10MHz

*3 : Channel-case

OUTLINE DRAWING

Unit: millimeters (inches)

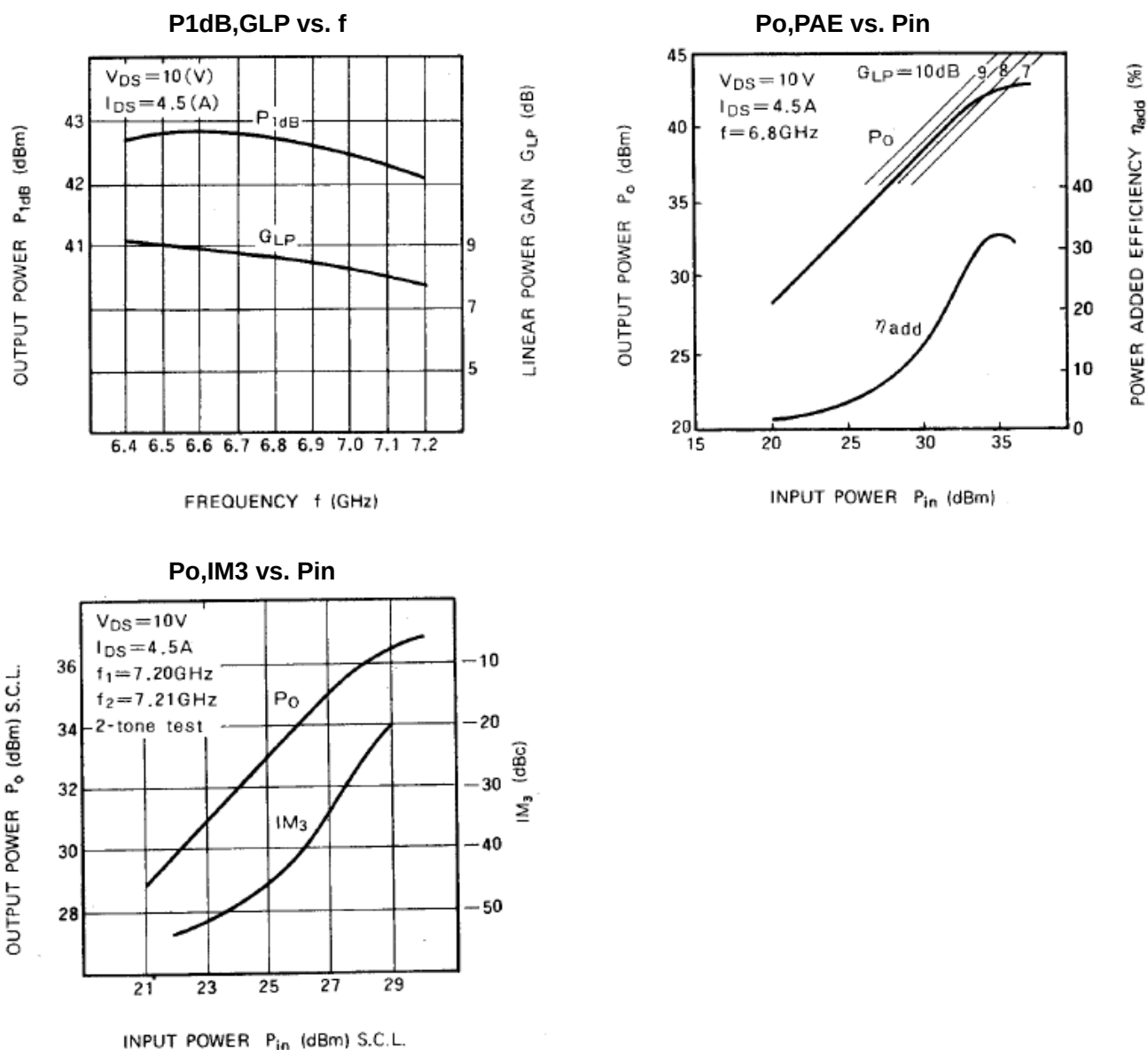


(1): GATE
(2): SOURCE (FLANGE)
(3): DRAIN

GF-18

Keep Safety first in your circuit designs!

Mitsubishi Electric Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measure such as (i) placement of substitutive, auxiliary circuits, (ii) use of non-flammable material or (iii) prevention against any malfunction or mishap.

MGFC42V6472 TYPICAL CHARACTERISTICS(Ta=25deg.C)**MGFC42V6472 S-parameters**(Ta=25deg.C , VDS=10(V),IDS=4.5(A))

f (GHz)	S Parameters(Typ.)							
	S11		S21		S12		S22	
	Magn.	Angle(deg.)	Magn.	Angle(deg.)	Magn.	Angle(deg.)	Magn.	Angle(deg.)
6.4	0.41	77	2.83	-95	0.068	-147	0.30	67
6.5	0.40	59	2.80	-111	0.072	-162	0.35	59
6.6	0.38	42	2.78	-127	0.075	-177	0.40	54
6.7	0.36	26	2.72	-143	0.078	167	0.42	48
6.8	0.33	11	2.64	-158	0.080	151	0.44	42
6.9	0.28	-3	2.60	-173	0.081	137	0.45	36
7.0	0.22	-20	2.57	171	0.082	122	0.44	32
7.1	0.17	-46	2.53	157	0.084	108	0.43	28
7.2	0.14	-91	2.50	141	0.086	93	0.40	26

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